

HMC441LP3E

Data Sheet

RF Amplifier IC, 13 dB Gain / 4.75 dB Noise, 6.5 GHz to 13.5 GHz, 5 V, HVQFN-16

Manufacturers Analog Devices, Inc

Package/Case QFN-16

Product Type RF Amplifiers

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for HMC441LP3E or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The HMC441LP3E is a broadband GaAs pHEMTMMIC Medium Power Amplifiers which operatebetween 6.5 and 13.5 GHz. The leadlessplastic QFN surface mount packaged amplifierprovides 14 dB of gain, +20 dBm saturated powerat 20% PAE from a +5V supply voltage. An optional gate bias is provided to allow adjustment of gain,RF output power, and DC power dissipation. This 50 Ohm matched amplifier does not require anyexternal components making it an ideal linear gainblock or driver for HMC SMT mixers.

Features Application

Gain: 14 dB Point-to-Point Radios

Saturated Power: +20 dBm @ 20% PAE Point-to-Multi-Point Radios

Single Supply Voltage: VSAT

50 Ohm Matched Input/Output LO Driver for HMC Mixers

16 Lead 3x3mm SMT Package: 9mm2 Military EW & ECM



Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC948LP3E
Analog Devices, Inc
LP3



Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



HMC358MS8GE Analog Devices, Inc MSOP-8

HMC253AQS24



HMC490

Analog Devices, Inc SMD



Analog Devices, Inc ST89E

HMC453ST89E



HMC618ALP3E

Analog Devices, Inc QFN-16



HMC463LP5E

Analog Devices, Inc QFN-32